

SIHH21N60E-T1-GE3

SIHH21N60E-T1-GE3 Information

	Transistors - FETs, MOSFETs - SingleonMOSFET N-CH 600V 20A POWERPAK8X88-PowerTDFNFor the pricing/inventory/lead time, please contact	
For Reference Only	us Website: https://www.heisener.com E-mail: salesdept@heisener.com	Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



SIHH21N60E-T1-GE3 Specifications

Manufacturer Part Number	SIHH21N60E-T1-GE3
Manufacturer	Vishay Siliconix
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Single
Package	8-PowerTDFN
Series	-
FET Type	N-Channel
Technology	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss)	600V
Current - Continuous Drain (Id) @ 25°C	20A (Tc)
Drive Voltage (Max Rds On, Min Rds On)	10V
Vgs(th) (Max) @ Id	4V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	83nC @ 10V
Input Capacitance (Ciss) (Max) @ Vds	2015pF @ 100V
Vgs (Max)	±30V
FET Feature	-
Power Dissipation (Max)	104W (Tc)
Rds On (Max) @ Id, Vgs	176 mOhm @ 11A, 10V
Operating Temperature	-55°C ~ 150°C (TJ)
Mounting Type	Surface Mount
Supplier Device Package	PowerPAK? 8 x 8
Package / Case	8-PowerTDFN
	Report errors?

SIHH21N60E-T1-GE3 Guarantees



Quality Guarantees

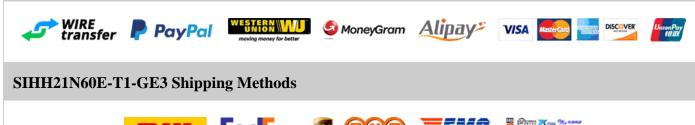
We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.

SERVICE BUARANTEE

Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

SIHH21N60E-T1-GE3 Payment Methods





If you have any question about SIHH21N60E-T1-GE3, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com